Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: | |
|---|--------|
| Glass | |
| Overall Height: | |
| 1.940 inches | |
| End Application: | |
| C-5m | |
| Voltage Rating In Volts Per Characteristic: | |
| 64.6 breakdown voltage, instantaneous | |
| Power Rating Per Characteristic: | |
| 1500.00 watts peak pulse output power | |
| Maximum Operating Tempurature Per Measurement Point: | |
| -65.00 degrees celsius ambient air and 175.00 degrees celsius ambient air | |
| Product Name: | |
| Diode, apu circuit | |
| Special Features: | |
| Reverse stand-off volatage: 51.7v, reverse leakage current: 5, breakdown voltage: 64.6v, test current: 20, maximum clamping vol | tage: |
| 97.1, peak pulse current: 15.4, temperature coefficient: 0.100, maximum reverse leakage current: 400 | |
| Special Test Features: | |
| Peak pulse power: 1500 watts, operating temperature: -65 to 175c, storage temperature: -65 to 175c, steady-state power dissipatio | n @ tl |
| = 75c (3/8"): 5 watts | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |

No

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